

KBP6005-KBP610/G

Single Phase 6.0Amp Glass passivated Bridge Rectifiers

Features Package

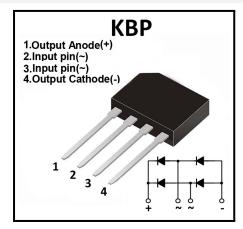
- Rating to 1000V PRV
- · Idea for printed circuit board
- · Reliable low cost construction utilizing molded plastic technique
- The plastic material has UL flammability classification 94V-0
- The G suffix is uses for photoresist chip, otherwise it is a knife scraping chip

MECHANICAL DATA

• Polarity : As marked on body

• Weight: 0.05 ounces, 1.52 grams

• Mounting position : Any



Maximum Ratings And Electrical Characteristics (@T_A=25°C unless otherwise noted)

Cumbal	Parameter	KBP	KBP	KBP	KBP	KBP	KBP	KBP	Unit
Symbol		6005	601	602	604	606	608	610	
V_{RRM}	Maximum repetitive peak reverse voltage	50	100	200	400	600	800	1000	V
V_{RMS}	Maximum RMS voltage	35	70	140	280	420	560	700	V
V_{DC}	Maximum DC blocking voltage	50	100	200	400	600	800	1000	V
I _{AV}	Maximum average forward rectified(With heatsink)	6.0					А		
IAV	current @T _C =105°C(Without heatsink)	3.0							
I _{FSM}	Peak Forward Surge Current@T _J =25°C	150					А		
	8.3ms single half sine-wave @T _J =125°C	120							
V_{F}	Maximum forward voltage at 6.0A DC	1.10			V				
	Maximum DC reverse current@T _J =25°C	5.0				uA			
I _R	at rated DC blocking voltage @T _J =125°C	500							
I_t^2	I _t ² Rating for fusing (3ms≤t≤8.3ms)	93.38			A _S ²				
CJ	Typical junction capacitance (Note 1)	46			pF				
$R_{ heta JC}$	Typical thermal resistance				°C/W				
	(Unit mounted on 30mmx30mmx1mm	3.0							
	Copper plate heatsink.)								
$R_{\theta JC}$	Typical thermal resistance	8.0				°C/W			
1,61C	(without heatsink)	8.0					C/VV		
TJ	Operation Temperature Range	-55 to +150				°C			
T _{STG}	Storage Temperature Range	-55 to +150							
	1								

Revision: 2022-Jan-1

Note:(1)Measured at 1MHz and applied reverse voltage of 4.0V D.C.





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Ratings And Characteristic Curves

Figure 1: FORWARD CURRENT DERATING CURVE

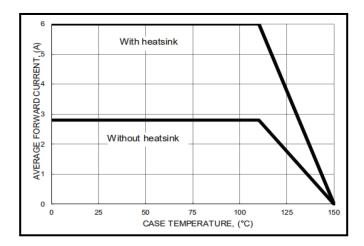


Figure 2: MAXIMUM NON-REPETITIVE SURGE CUR-

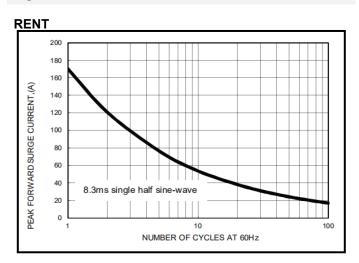


Figure 3:TYPICAL JUNCTION CAPACITANCE

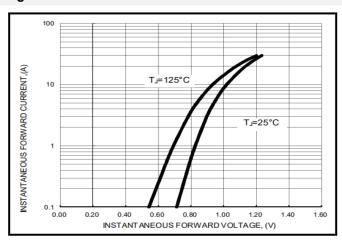


Figure 4:TYPICAL FORWARD CHARACTERISTICS

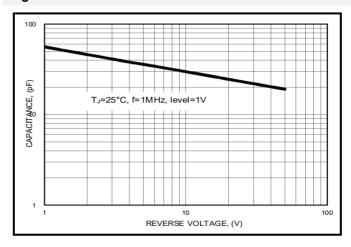
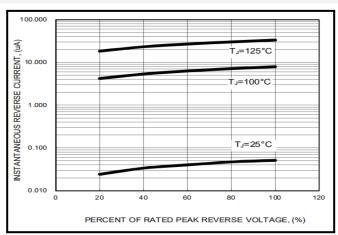


Figure 5:TYPICAL REVERSE CHARACTERISTICS



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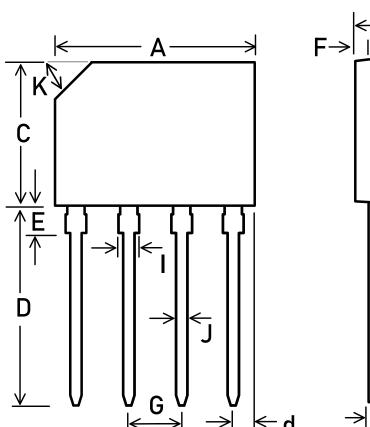


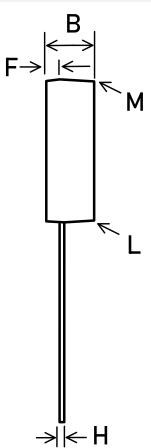


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Outline Drawing -KBP





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OVMDOL	MILLIMETER					
SYMBOL	MIN.	MAX.				
А	14.2	14.7				
В	3.30	3.60				
С	10.2	10.6				
D	13.8	14.4				
d	1.40	1.70				
E	1.80	2.20				
F	0.80	1.10				
G	3.71	3.91				
Н	0.30	0.55				
I	1.22	1.42				
J	0.76	0.86				
K	2.7 x 45°					
L	_	3°				
М	_	2°				